



3rd Workshop on Robustness of IoT Devices

September 16-17, 2020
Peppermill Resort and Casino
2707 S Virginia St, Reno, NV 89502

Co-located at 2020 EOS/ESD Symposium

- IoT catalyzes a change in the way device robustness is implemented and tested.
- Be there when the new directions are set for technical solutions, standards, and shared responsibilities in industry.
- Meet with today's experts and industry leaders on the Robustness of IoT Devices.
 - Invited talks by IoT technology leaders
 - Open workshop style debates
 - Interactive expert panel discussion



Education



Symposium

ASSOCIATION

Welcome by the Management Team

Together with the technical program committee, we would like to welcome you to our third Workshop on Robustness of IoT Devices on September 16 & 17 in conjunction with the 2020 EOS/ESD Symposium in Reno, NV, USA. During this worldwide crisis, our way of living and working has been challenged in an unprecedented way, including the cancellation of many established and appreciated scientific meetings. We are looking forward to a workshop that allows us to meet in person to discuss results and open topics of our technical fields. The crisis is, to some extent, a stress test for the 'robustness' of our social and technical systems. It shows us how important it is to study and plan for situations which are far outside our usual 'range of operation'. With the continued and accelerated growth of IoT devices and applications which reach far into our private life and impact the safety of billions, the consideration of robustness of IoT devices is an absolute necessity.

You might ask the question, "what is different in the robustness of an IoT device compared to electronic devices and systems we have produced and used for decades?" The answer is somehow trivial. There is no difference if the device is designed and tested for a specific, well-defined mission profile. However, continually growing and expanding IoT applications need semiconductor devices which have been developed for very different usage. Examples include a 5G baseband IC or an AI accelerator, which can end up in very harsh ambient conditions. A dedicated design would both delay the innovations and not be economically feasible for lower volume parts. The challenge is to establish methods to make a solid judgment of the robustness of this device used for the different mission profiles. This needs the consideration of reliability aspects as well as immunity against electrical transients. As the PCB and module design has a substantial impact on the outcome of the assessment, the treatment of co-design and co-evaluation is crucial to assess the robustness of the IoT devices.

We have created a dedicated workshop to offer a holistic discussion of robustness, including lifetime aspects as well as transient stress situations. The workshop is a unique forum to bring the IC design community, the system design community, and application development together for this topic. The mission of the Workshop on Robustness of IoT Devices has been established as a stand-alone event following a period of incubation under the umbrella of the EOS/ESD Symposium. This year's workshop is focused on the development of new methodologies supporting the fast and versatile assessment of mission profiles and the aspects of heterogeneous integration, which adds different technologies and materials (other than silicon) to the robustness considerations.

We wish you an inspiring workshop with the best possible exchange, and we are looking forward to seeing you in September.

Best regards

Ann Concannon, Texas Instruments

Mirko Scholz, Infineon Technologies AG

Harald Gossner, Intel Duetschland GmbH

Register Online!

<http://www.cvent.com/d/xnqvhl>

Take advantage of components of the EOS/ESD Symposium

Hospitality Suites

To maintain the objectives of the Symposium, EOS/ESD Association, Inc. encourages all exhibitors and guest organizations to schedule their hospitality and other social events at times that do not conflict with the Symposium presentations and educational activities.

Age Limits

No one under 18 years of age will be admitted to the exhibit hall.

Unauthorized Solicitation

Solicitation of business on the premises during the EOS/ESD Symposium by manufacturers or others who are not participating as exhibitors is prohibited.

Recording

Video and/or audio recording of Symposium events is prohibited without the prior written authorization of EOS/ESD Association, Inc.

Welcome Reception

A welcome reception for all attendees will be held on Monday, September 14, at 6:00 p.m. in the exhibit hall. Network with your colleagues, share your ESD work experiences with others, view the exhibits, or simply pass the time meeting new people and making new friends. The 2020 Steering Committee will greet you and answer any questions regarding the Symposium.

Annual Meetings and Awards Breakfast

The annual meeting and awards breakfast for all registered attendees and exhibitors will be held Tuesday, September 15, at 7:30 a.m. Following breakfast, General Chair, Lorenzo Cerati, will officially open the Symposium. Vice General Chair, Wolfgang Stadler, will present the 2019 EOS/ESD Symposium paper awards. Technical Program Chair, Souvick Mitra, will cover highlights of the 2020 technical program. Association President, Alan Righter, will present the Association's annual report. Awards Chair, Charvaka Duvvury, will present the 2020 Association awards.

Professional and Technical Women's Reception

The Professional and Technical Women's Reception provides a friendly environment where women in the field of ESD can network and share work experiences. This year's reception will be held on Monday, September 14, from 5:00 p.m. to 6:00 p.m.

University Students/Professors Invited to Wednesday Breakfast with ESDA Management

Wednesday, September 16, 7:00 a.m.-8:00 a.m.

First Time Attendee Social Hour

Wednesday, September 16, 12:30 p.m.-1:00 p.m.

Young Professionals Social Reception

Wednesday, September 16, 1:00 p.m.-1:30 p.m.

On-Site Registration Hours

Registration will be open at the following times:

Sunday, September 13 7:30 a.m. - 5:00 p.m.

Monday, September 14 7:30 a.m. - 5:00 p.m.

Tuesday, September 15 7:30 a.m. - 5:00 p.m.

Wednesday, September 16 7:30 a.m. - 5:00 p.m.

Thursday, September 17 7:30 a.m. - 5:00 p.m.

IoT Workshop \$250

Includes all items in IoT workshop program, plus EOS/ESD Symposium exhibits, breakfasts, and receptions.

General Chair's Reception

Lorenzo Cerati invites attendees and exhibitors to the general chair's reception on Wednesday, September 16, from 7:00 pm to 9:00 pm. **Poster presentations of technical papers from all sessions will be on display.**

Don't miss this opportunity to network and share informal conversation with authors, industry professionals, and peers.

WEDNESDAY, SEPTEMBER 16, 2020

- Welcome 1:00 p.m. - 1:10 p.m. IoT Workshop Welcome
- 1:10 p.m. - 1:55 p.m. Keynote: **Advanced Packaging Architectures and Associated Robustness Challenges**
- 1:55 p.m. - 4:50 p.m. **IoT I - Devices & Technologies for Emerging Markets**
- 1:55 p.m. - 2:20 p.m. **1.1 - Low Power Technologies for IoT**
- 2:20 p.m. - 2:45 p.m. **1.2 - MEMs Robustness in IOT Applications**
- 2:45 p.m. - 3:10 p.m. **1.3 - Active Polymer Interposers as Base for Robust Heterogenous IoT Systems**
- 3:40 p.m. - 4:25 p.m. **1.4 (Invited) - Transient Pulse Characterization for IC and Modules**
- 4:25 p.m. - 4:50 p.m. **1.5 - Robust Wireless Connectivity for IoT Applications**
- Workshop B5:25 p.m. - 6:40 p.m. B.3 IoT Expert Panel - Including Robustness of IoT Devices in the Product Development
- Reception 7:00 p.m. - 9:00 p.m. General Chair's Reception **Open to all IoT Attendees and Exhibitors!**

THURSDAY, SEPTEMBER 17, 2020

- 9:00 a.m. - 9:45 a.m. **IoT II - Methodologies to Serve a Fragmented Market with Wide Range of Reliability and ESD**
- 9:00 a.m. - 9:45 a.m. **2.1 (Invited) - High Reliability Assessment**
- 9:45 a.m. - 10:30 a.m. **2.2 (Invited) - Design Methods for Robust Aging Assessment and Validation of Automotive and Hi Reliability IP**
- 10:50 a.m. - 11:35 a.m. **2.3 (Invited) - EDA Tools Supporting Heterogeneous Integration in 2.5D and 3D**
- 11:35 a.m. - 12:00 p.m. **2.4 - A Novel Look at Transient AMR Representation**
- 12:00 p.m. - 12:25 p.m. **2.5 - Walking Wounded Loophole in System Level ESD Qualification**
- 12:25 p.m. - 12:30 p.m. IoT Workshop Closing Remarks

Register Online!

<http://www.cvent.com/d/xnqvhl>

KEYNOTE

Wednesday, September 16

1:10 p.m. - 1:55 p.m.



Advanced Packaging Architectures and Associated Robustness Challenges

Ravi Mahajan, Intel Fellow

Advanced packaging technologies are critical enablers of Heterogeneous Integration (HI) because of their importance as compact, power efficient platforms.. This talk will trace the evolving role of packaging over the past decades and examine its value as an HI platform. Different packaging architectures will be compared primarily on the basis of their physical interconnect capabilities. Key features in leading edge 2D and 3D technologies, such as EMIB, Silicon Interposer, Foveros and Co-EMIB will be described and a roadmap for their evolution will be presented. Challenges and opportunities in developing robust advanced package architectures will be discussed. The talk will conclude with a discussion of overall opportunities and challenges in driving the package roadmap forward.

Ravi Mahajan is an Intel Fellow and the Director of Pathfinding for Assembly and Packaging technologies for future silicon nodes. Ravi also represents Intel in academia through research advisory boards, conference leadership and participation in various student initiatives.

Ravi has led Pathfinding efforts to define Package Architectures, Technologies and Assembly Processes for multiple Intel silicon nodes since 2000, spanning 90nm, 65nm, 45nm, 32nm, 22nm and 7nm silicon. Earlier in his Intel career, he spent eight years as a Technologist and manager for the Thermal-Mechanical Tools and Analysis Group. In these roles, Ravi oversaw a Thermal-Mechanical Lab chartered with delivering detailed thermal and mechanical characterization of Intel's packaging solutions for current and future processors. His group was also responsible for the collaborative development of a number of technologies for the thermal management of micro-electronics, high precision thermal and thermo-mechanical characterization and modeling techniques.

A prolific inventor and recognized expert in microelectronics packaging technologies, Ravi holds more than 50 patents, including the original patents for silicon bridges that became the foundation for Intel's EMIB technology. His early insights also led to high-performance, cost-effective cooling solutions for high-end microprocessors and the proliferation of photo-mechanics techniques used for thermo-mechanical stress model validation.

Ravi joined Intel in 1992 after earning a bachelor's degree from Bombay University, a master's degree from the University of Houston, and a Ph.D. from Lehigh University, all in Mechanical Engineering. His contributions during his Intel career have earned him numerous industry honors, including the SRC's 2015 Mahboob Khan Outstanding Industry Liaison Award, the 2016 THERMI Award from SEMITHERM, the 2016 Allan Kraus Thermal Management Medal & the 2018 InterPACK Achievement award from ASME, the 2019 "Outstanding Service and Leadership to the IEEE" Awards from IEEE Phoenix Section & Region 6 and the 2020 Richard Chu ITherm Award for Excellence.

He is an IEEE EPS Distinguished Lecturer. He is one of the founding editors for the Intel Assembly and Test Technology Journal (IATTJ) and currently VP of Publications & Managing Editor-in-Chief of the IEEE Transactions of the CPMT. Additionally he has been long associated with ASME's InterPACK conference and was Conference Co-Chair of the 2017 Conference. Ravi is a Fellow of two leading societies, ASME and IEEE. He was named an Intel Fellow in 2017.

Technical Sessions: Wednesday, September 16

I 1.1 Low Power Technologies for IoT

Michael Wu, Jam Wem Lee, TSMC

The IoT devices require the low cost and low power to be perfectly matched to mature technology on low power options as a quite sustainable nodes in a long run. Specific challenges for silicon foundry technology are to provide extreme low leakage power clamps to save the battery life and to deliver solutions for HMM (IEC61000-4-2) requirements.

I 1.2 MEMs Robustness in IOT Applications

Barry O'Connell, TDK-InvenSense

MEMs sensors are becoming ubiquitous in IOT devices. This paper focusses on the sensor sensitivity and robustness requirements involved in different applications and the design tradeoffs associated with these competing forces. It addresses some of the common application requirements, for example drop and tumble requirements, and methods not currently covered by industry standard testing.

I 1.3 Active Polymer Interposers as Base for Robust Heterogenous IoT Systems

Karen Shrier, Electronic Polymers; Harald Gossner, Intel

Downscaled IoT systems can efficiently be integrated as 2.5D or 3D package systems with various functionality dies in smallest volume. Active polymer interposers offer an attractive alternative to costly Silicon based interposers offering integrated ESD protection at lowest parasitic capacitance.

I 1.4 (Invited) Transient Pulse Characterization for IC and Modules

Heinrich Wolf, Fraunhofer EMFT

Considering the versatility of IoT device applications the robustness testing of IoT ICs and modules must be revisited. The presentation discusses real world examples and proposes an efficient method for transient stress testing at module and board level. Together with the characterization of the stand-alone ICs this enables the co-design of IC and PCB for robustness goals of the specific IoT mission profile.

I 1.5 Robust Wireless Connectivity for IoT Applications

Stefan Dannenberger, Texas Instruments

The backbone of the Internet of Things (IoT) is connectivity. Sensor and actuator nodes are connected to the cloud through central hubs. This talk will discuss low-power wireless connectivity solutions for the IoT, focusing on wireless MCU radio architecture, important radio parameters and communication standards, and the environmental influences to be considered for robust and reliable communication.

WORKSHOPS: WEDNESDAY, SEPTEMBER 16

B.3 IoT Expert Panel - Including Robustness of IoT Devices in the Product Development

Mirko Scholz, Infineon Technologies AG

Several EDA tools and measurement and characterization methods are used to support the design of robust IoT devices during product development. The panel discusses the application of these tools in the daily design work. Also the panel reviews the requirements that ensure the robustness of IoT devices in their diverse applications.

Technical Sessions: Thursday, September 17

I 2.1 (Invited) Reliability and IoT Devices: IoT Mission Profiles, Design Challenges, and Methods

Scott Martin, Subhadeep Ghosh, Texas Instrument

As IoT proliferates throughout the public domain into automobiles, factories, and buildings, reliability of these IoT devices must also scale. A fundamental aspect of reliability is that the device must support the mission profile. The talk provides the key aspects how IoT device mission profiles is integrated into a design strategy.

I 2.2 (Invited) Design Methods for Robust Aging Assessment and Validation of Automotive and Hi Reliability IP

David Burnell, Cadence Design Systems

Today's ecosystem is mostly geared for consumer-grade designs where aging analysis tools are evolving but most solutions today are just running circuit simulators with aging enabled. Automotive and industrial quality requires a different mindset build on a robust IP design environment supports aging assessments at all levels. In this presentation we will cover the methods, tools and flows to enable intelligent evaluations throughout the circuit hierarchy and design process.

I 2.3 (Invited) User Friendly Full Chip ESD Design Verification Platform

Frank Feng, Synopsys

A library based ESD design rule writing python utility is presented which can greatly help users to develop their different requirements on IO, power/ground ESD protection circuits, and automatically clustering power clamping devices physically for a flexible and easy-to-use (IoT) device design. A VUE GUI assists the user to understand results of ESD layout parasitic check breakdown by layer.

I 2.4 A Novel Look at Transient AMR Representation

Harald Gossner, Intel

A concise and meaningful description of transient absolute maximum ratings (tAMR) is one of today's pain points for specifying ICs. A novel AMR diagram is proposed which contains maximum absolute ratings over all time domains. This includes the lifetime degradation regime as well as worst case power to fail characteristics.

I 2.5 Walking Wounded Loophole in System Level ESD Qualification

James Karp, Xilinx

"Walking wounded" are parts that have been damaged but are not detected as failures. Component-level ESD qualification results detect failures of functional FPGAs. Contrarily System-level ESD Qualification with JTAG detect no failures of the same FPGA. A proposal is made to match component and system-level pass/fail criteria.

Registration

1 Please Print or Type (Your name and company will appear on badge and/or certificate exactly as written below.)

Mr./Mrs./Ms.: _____ First Name: _____ Last Name: _____

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IoT Workshop \$250
Includes all items in IoT workshop program September 16-17, 2020
Plus exhibits and all symposium breakfasts and receptions

Register Online!
<http://www.cvent.com/d/xnqvhl>

4 Payment: Company purchase orders not accepted.

Check (Make payable to EOS/ESD Association, Inc.)

TOTAL ENCLOSED \$ _____

Type: __ Visa® __ Master Card® __ AMEX® __ Discover®

Credit Card # _____ Expiration Date: _____ Code: _____

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Accommodations

Room Rates

[Peppermill Hotel Reservations](#) or
<https://book.passkey.com/event/50002217/owner/7268/home>

- Call in information – 1-800-282-2444 (reference group code: AESDA20)
- Book reservations by 8/26/2020 (Please book early as a limited number of hotel rooms are available at the group rate)
- Rate – \$129.00+Tax (Peppermill Tower) & \$149+tax (Tuscany Tower)

Note: The Resort Fee is included in the rate and includes the following:

- Resort fee includes high-speed internet access throughout the hotel (including hotel rooms, public space, meeting space, etc.), in-room coffee makers, use of the health club, pool, valet, access to the parking garage and surface parking, concierge, local and #800 phone calls, and shuttle service to and from the airport.

Note: Complimentary internet access in meeting rooms (only for guests staying at The Peppermill Resort Hotel).

UNAUTHORIZED HOUSING

Housing block “pirates” now routinely “poach” event attendees and exhibitors!

Pirating companies gather group’s contact information from published or online directories. They call attendees leaving the impression that they are an “official” housing representative. They will also frequently cite an imminent sell-out of the block while urging you to secure housing immediately. Another tactic is to offer a room rate that is significantly less than the official rate. Offered rooms may be substandard or at other properties. Please do not respond to these solicitations or book your rooms with any housing organizations that “claim” to represent EOS/ESD Association, Inc. Booking via the hotel link or calling the number we provided are the only safe and reliable methods for booking your hotel reservations.

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